NSN 5962-01-363-2462

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View Online at https://aerobasegroup.com/nsn/5962-01-363-2462

Maximum Power Dissipation Pating
Maximum Power Dissipation Rating: 1.0 watts
Operating Tempurature Range:
-55.0 to 125.0 degrees celsius
Storage Tempurature Range:
-65.0 to 150.0 degrees celsius
Features Provided:
Burn in and electrostatic sensitive and monolithic and programmed
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Input Circuit Pattern:
21 input
Criticality Code Justification:
Feat
Case Outline Source And Designator:
D-9 mil-m-38510
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
7.0 volts power source
Memory Device Type:
Ram
Memory Capacity:
64kx4
Special Features:
Nuclear hardness critical item
Nuclear Hardness Critical Feature:
Hardened
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
24 printed circuit
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Demilitarization: Yes - demil/mli

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